

Single 2-input OR Gate

General Description

The ETQ74AUP1G32 is a single 2-input OR Gate, which can operate from a 0.8V to 3.6V supply. This device is fabricated with advanced CMOS technology to achieve ultra-high speed with high output drive.

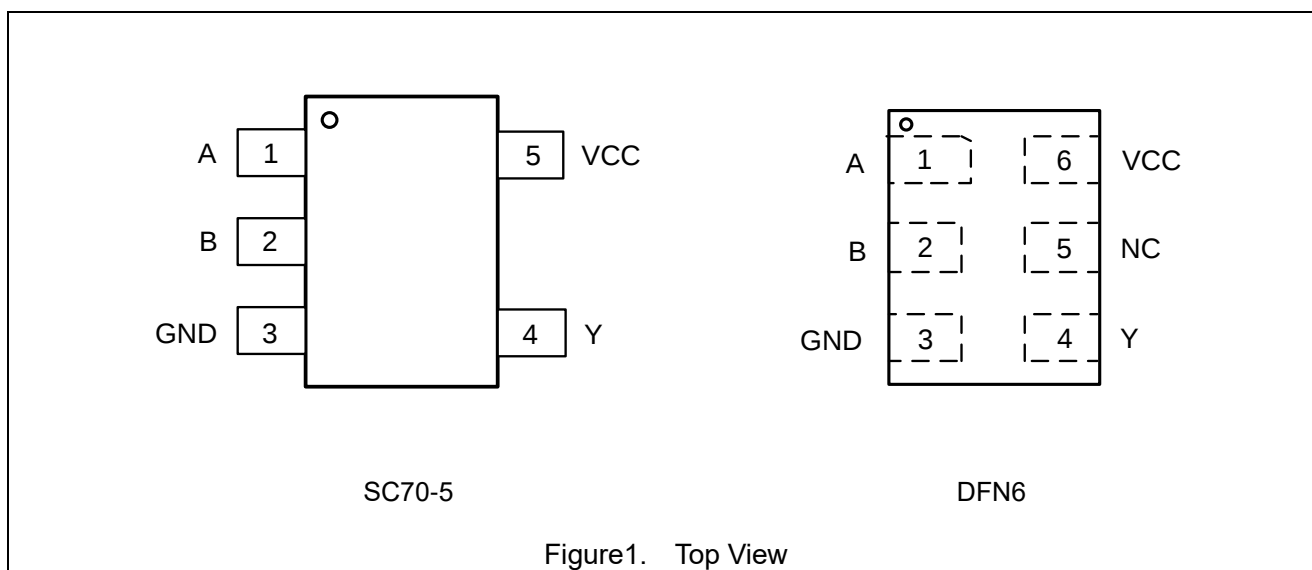
Features

- Designed for 0.8V to 3.6V VCC Operation
- Low static power consumption; ICC = 0.7μA (maximum)
- 4mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- These Devices are Pb-Free and are RoHS Compliant
- Multiple Package Options Automotive AEC-Q100 Grade 1 Qualified
 - Ambient temperature range of -40°C to +125°C
 - ESD HBM 4KV PASS
 - ESD CDM 1KV PASS
 - Latch Up Current to 100mA PASS

Device Information

Part No.	Package	MSL
ETQ74AUP1G32	SC70-5 (1.3mm×2.1mm)	3
ETQ74AUP1G32Y	DFN6 (1.0mm×1.5mm)	1
ETQ74AUP1G32N	DFN6 (1.0mm×1.0mm)	1

Pin Configuration

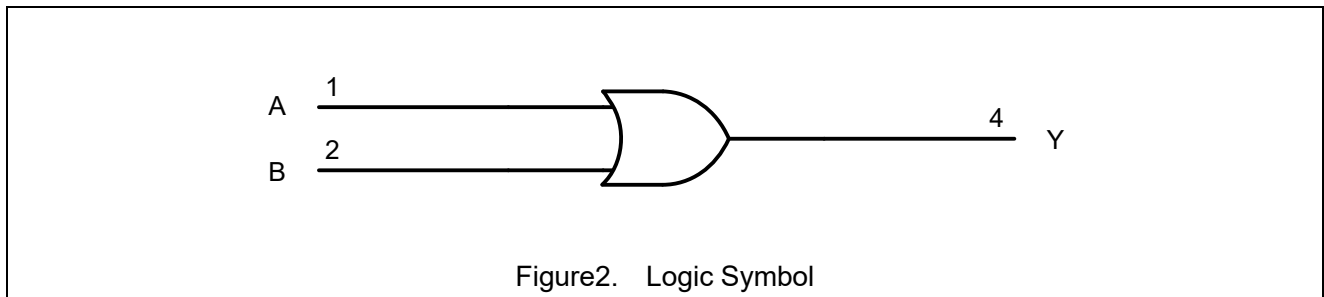


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Pin Function

Pin No.		Pin Name	Function
SC70-5	DFN6		
1	1	A	Input A
2	2	B	Input B
3	3	GND	Ground
4	4	Y	Output Y
/	5	NC	No Connect
5	6	VCC	Supply Voltage

Block Diagram



Functional Description

Function Table

Input		Output
A	B	Y
L	L	L
L	H	H
H	L	H
H	H	H

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Absolute Maximum Ratings

Symbol	Parameter		Value	Unit
V _{CC}	DC Supply Voltage		-0.5 to 4.6	V
V _I	DC Input Voltage ⁽¹⁾		-0.5 ≤ V _I ≤ +4.6	V
V _O	DC Output Voltage Output in Higher or Low State		-0.5 to 4.6	V
I _{IK}	DC Input Diode Current	V _I < GND	-50	mA
I _{OK}	DC Output Diode Current	V _O < GND, V _O > V _{CC}	±50	mA
I _O	DC Output Sink Current		±20	mA
I _{CC}	DC Supply Current per Supply Pin		±50	mA
I _{GND}	DC Ground Current per Supply Pin		±50	mA
T _{STG}	Storage Temperature Range		-65 to 150	°C
T _L	Lead Temperature, Soldering 10 Seconds		260	°C
T _J	Max Junction Temperature		150	°C
V _{ESD}	ESD Classification	Human Body Model ⁽²⁾	±4000	V
		Charged Device Model ⁽³⁾	±1000	
I _{LU}	Latch up Current Above V _{CC} and GND at 125°C ⁽⁴⁾		±100	mA

Stresses exceeding those listed in this table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Note1: IO absolute maximum rating must be observed;

Note2: HBM tested per AEC-Q100-002(EIA/JESD22-A114);

Note3: CDM tested per AEC-Q100-011(EIA/JESD22-C101);

Note4: Latch up Current Maximum Rating tested per AEC-Q100-004(EIA/JESD78E);

Thermal Characteristics

Symbol	Package	Ratings	Value	Unit
R _{θJA}	SC70-5	Thermal Characteristics, Thermal Resistance, Junction-to-Air	300	°C/W
	DFN6(1×1.5)		440	
	DFN6(1×1)		440	

Recommended Operating Conditions

Symbol	Parameter		Min	Max	Unit
V _{CC}	DC Supply Voltage Operating		0.8	3.6	V
V _{IN}	DC Input Voltage		0	3.6	V
V _{OUT}	DC Output Voltage (High or Low State)		0	3.6	V
T _A	Operating Temperature Range		-40	125	°C
t _r , t _f	Input Rise and Fall Time	V _{CC} = 0.8V to 3.6V	0	20	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied.

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Electrical Characteristics

DC Electrical Characteristics

Symbol	Parameter	Condition	V _{CC} (V)	T _A = 25°C			-40°C ≤ T _A ≤ 85°C		Unit
				Min	Typ	Max	Min	Max	
V _{IH}	High-Level Input Voltage		0.8	0.75V _{CC}			0.75V _{CC}		V
			0.9 to 1.95	0.7V _{CC}			0.7V _{CC}		
			2.3 to 2.7	1.6			1.6		
			3.0 to 3.6	2.0			2.0		
V _{IL}	Low-Level Input Voltage		0.8			0.25V _{CC}		0.25V _{CC}	V
			0.9 to 1.95			0.3V _{CC}		0.3V _{CC}	
			2.3 to 2.7			0.7		0.7	
			3.0 to 3.6			0.9		0.9	
V _{OH}	High-Level Output Voltage	I _{OH} =-20μA	0.8 to 3.6	V _{CC} -0.1			V _{CC} -0.1		V
		I _{OH} =-1.1mA	1.1	0.82	1.02		0.77		
		I _{OH} =-1.7mA	1.4	1.11	1.32		1.03		
		I _{OH} =-1.9mA	1.65	1.32	1.58		1.30		
		I _{OH} =-2.3mA	2.3	2.05	2.24		1.97		
		I _{OH} =-3.1mA		1.9	2.22		1.85		
		I _{OH} =-2.7mA	3.0	2.72	2.95		2.67		
		I _{OH} =-4.0mA		2.6	2.92		2.55		
V _{OL}	Low-Level Output Voltage	I _{OL} =20μA	0.8 to 3.6			0.1		0.1	V
		I _{OL} =1.1mA	1.1		0.11	0.33		0.33	
		I _{OL} =1.7mA	1.4		0.12	0.31		0.37	
		I _{OL} =1.9mA	1.65		0.11	0.31		0.35	
		I _{OL} =2.3mA	2.3		0.14	0.31		0.33	
		I _{OL} =3.1mA			0.19	0.44		0.45	
		I _{OL} =2.7mA	3.0		0.11	0.31		0.33	
		I _{OL} =4.0mA			0.16	0.44		0.45	
I _{IN}	Input Leakage Current	V _{IN} = V _{CC} or GND	0 to 3.6			±0.1		±0.2	μA
I _{OFF}	Power Off Leakage Current	V _{IN} = 3.6 V or V _{OUT} = 3.6 V	0			±0.2		±0.5	μA
ΔI _{OFF}	Additional Power Off Leakage Current	V _{IN} or V _{OUT} = 0~3.6 V	0~0.2			±0.2		±0.6	μA
I _{CC}	Quiescent Supply Current	V _{IN} = 3.6V or GND	3.6			±0.2		±0.7	μA

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ΔI_{CC}	Additional Quiescent Supply Current	$V_{IN} = 2.7V$	3.3			60		90	μA
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Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC Electrical Characteristics

$t_r = t_f = 2.5ns$

Symbol	Parameter	Condition	$V_{CC}(V)$	$T_A = 25^\circ C$			$-40^\circ C \leq T_A \leq 85^\circ C$		Unit
				Min	Typ	Max	Min	Max	
t_{PLH} t_{PHL}	Propagation Delay (Figure3 And 4)	$C_L = 5 pF^{(5)}$	0.8	12.3	31.8	117	10.9	332	ns
			1.2	4.7	8.2	17.3	4.3	18.5	
			1.5	3.2	5.2	10.5	2.8	11.9	
			1.8	2.5	3.8	7.9	2.2	9.2	
			2.5	1.8	2.5	5.7	1.5	6.6	
			3.3	1.5	1.9	4.8	1.2	5.4	
		$C_L = 10 pF^{(5)}$	0.8	13.4	33.5	122	11.9	342	ns
			1.2	5.1	8.8	18.3	4.7	19.4	
			1.5	3.5	5.5	11.2	3.1	12.6	
			1.8	2.8	4.1	8.4	2.4	9.7	
			2.5	2.0	2.8	6.0	1.7	6.9	
			3.3	1.6	2.2	5.0	1.3	5.7	
		$C_L = 15 pF^{(5)}$	0.8	14.5	33.9	127	12.8	352	ns
			1.2	5.5	9.5	19.3	5.1	20.5	
			1.5	3.8	6.0	11.8	3.3	13.2	
			1.8	3.0	4.5	8.9	2.6	10.2	
			2.5	2.1	3.0	6.3	1.8	7.3	
			3.3	1.7	2.3	5.3	1.4	6.0	
		$C_L = 30 pF^{(5)}$	0.8	17.6	34.3	133	15.5	382	ns
			1.2	6.7	11.3	22.2	6.2	23.5	
			1.5	4.6	7.2	13.6	4.0	15.3	
			1.8	3.6	5.4	10.2	3.1	11.7	
			2.5	2.5	3.6	7.3	2.2	8.4	
			3.3	2.0	2.8	6.0	1.7	6.9	

Note5. C_L includes probe and jig capacitance.

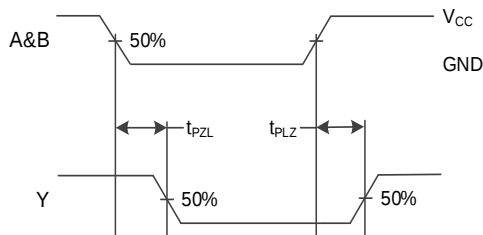
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Capacitance Characteristics

Symbol	Parameter	Condition		Typical	Unit
C _{IN}	Input Capacitance	V _{CC} = 3.6V, V _I = 0 V or V _{CC}		2	pF
C _O	output capacitance	V _{CC} = 0V, V _{OUT} = GND		3	pF
C _{PD}	Power Dissipation Capacitance ⁽⁶⁾	1 MHz, V _I = 0 V to V _{CC}	V _{CC} = 0.8V	7.6	pF
			V _{CC} = 1.2V	8.1	
			V _{CC} = 1.5V	8.5	
			V _{CC} = 1.8V	8.6	
			V _{CC} = 2.5V	9.0	
			V _{CC} = 3.3 V	9.6	

Note6. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)} = C_{PD} \times V_{CC} \times f_{in} + I_{CC} \times C_{PD}$ is used to determine the no-load dynamic power consumption; $P_D = C_{PD} \times V_{CC}^2 \times f_{in} + I_{CC} \times V_{CC} \times Fig.$

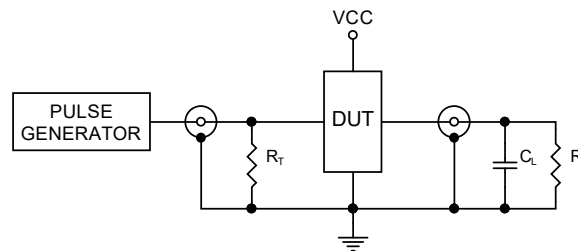
AC Test Circuit



PROPAGATION DELAYS

$t_R = t_F = 2.5 \text{ ns}$, 10% to 90%;
 $f = 1 \text{ MHz}$; $t_W = 500 \text{ ns}$

Figure 3. Switching Waveforms



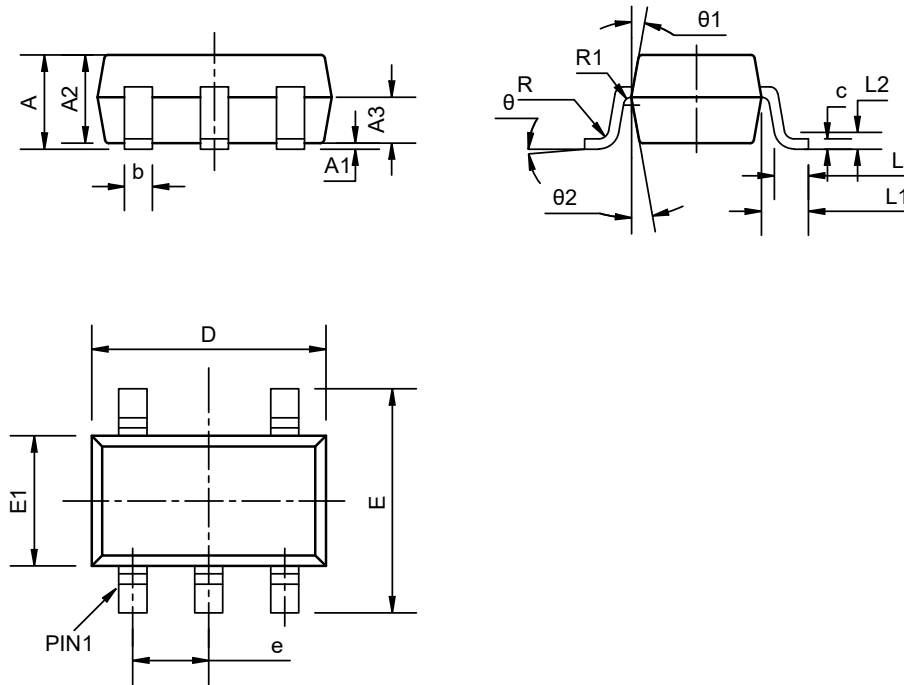
$R_T = 50\Omega$ (typ)

Figure4. Test Circuit

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Package Dimension

SC70-5

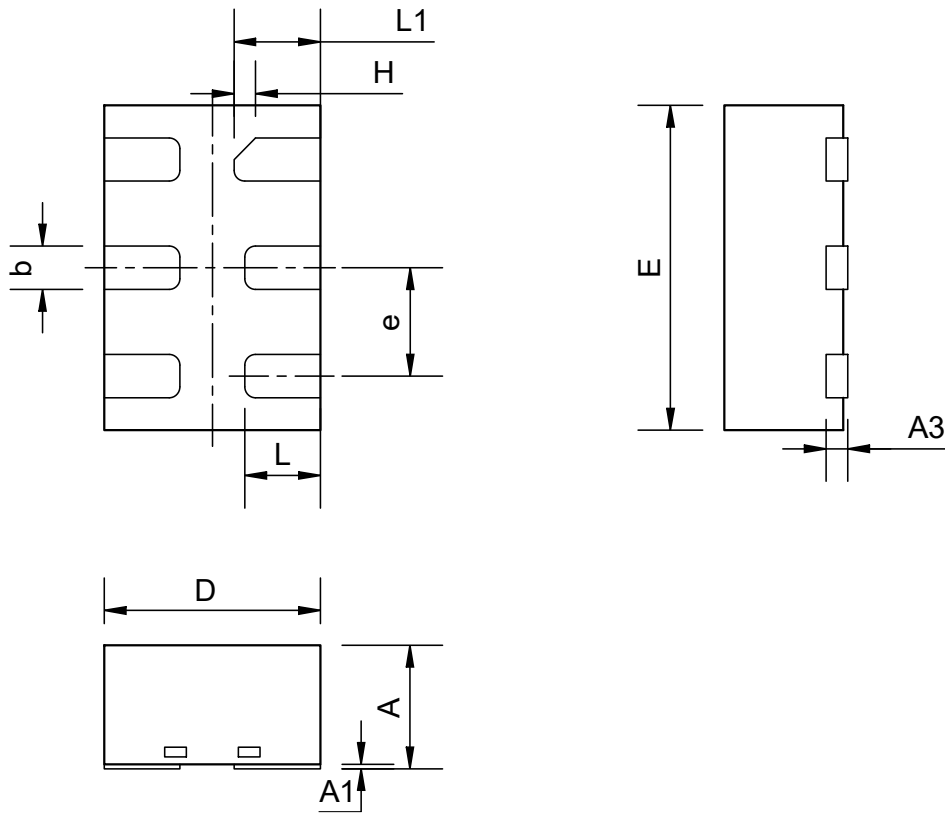


COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX
A	0.85	--	1.05
A1	0	--	0.10
A2	0.80	0.90	1.00
A3	0.47	0.52	0.57
b	0.23	--	0.33
c	0.12	--	0.18
D	2.02	2.07	2.12
E	2.20	2.30	2.40
E1	1.25	1.30	1.35
e	0.60	0.65	0.70
L	0.28	0.33	0.38
L1	0.50REF		
L2	0.15BSC		
R	0.10	--	--
R1	0.10	--	0.25
θ	0°	--	8°
θ_1	6°	9°	12°
θ_2	6°	9°	12°

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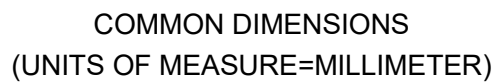
DFN6(1.0×1.5)



COMMON DIMENSIONS
(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX
A	0.50	--	0.60
A1	0	0.02	0.05
A3	0.10REF		
b	0.15	0.20	0.25
D	0.90	1.00	1.10
E	1.40	1.50	1.60
e	0.40	0.50	0.60
H	0.10REF		
L	0.30	0.35	0.40
L1	0.35	0.40	0.45

DFN6(1×1)

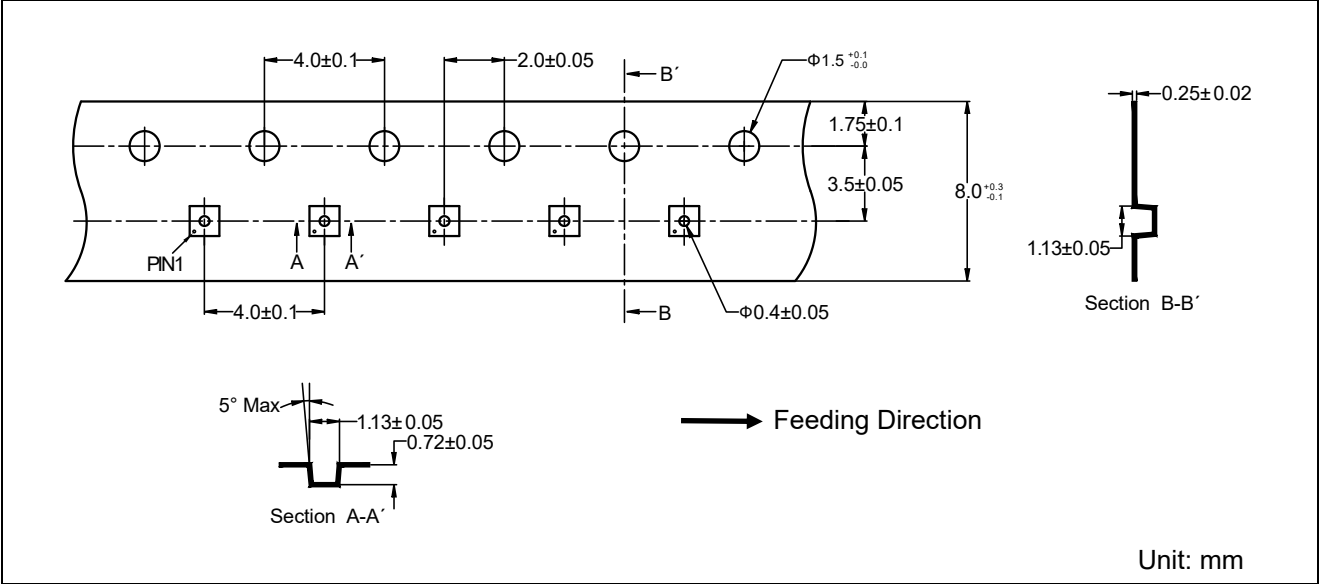


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Tape Information

DFN6(1×1)



Revision History and Checking Table

Version	Date	Revision Item	Modifier	Function & Spec Checking	Package & Tape Checking
0.0	2025-05-08	Preliminary Version	Yuyifan	Yangxiaoxu	Liujy